Phase diagram of the bose Hubbard model

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Abstract

The rst reliable analytic calculation of the phase diagram of the bose gas on a d-dim ensional lattice with on-site repulsion is presented. In one dim ension, the analytic calculation is in excellent agreement with the numerical Monte Carlo results. In higher dimensions, the deviations from the Monte Carlo calculations are larger, but the correct shape of the Mott insulator lobes is still obtained. Explicit expressions for the energy of the Mott and the \defect" phase are given in a strong-coupling expansion.

Strongly interacting quantum systems continue to challenge theoretical physics. Ferm ionic examples of strong correlations include high temperature superconductors, heavy ferm ion materials and metal-insulator transitions. The study of these systems has been con ned to either num erical simulations which are plaqued by nite-size e ects (with the notable exception of the in nite-dimensional expansion) or uncontrollable approximations. Sim ilar problems arise in strongly interacting bosonic systems which have attracted a lot of recent interest [14]. Physical realizations include short correlation length superconductors, granular superconductors, Josephson arrays, and the dynamics of ux lattices in type II superconductors. The relevant physics of these problems is contained in the bose Hubbard Ham iltonian which describes the competition between kinetic energy and potential energy e ects. Various aspects of this model were investigated analytically by mean-eld theory [1,5], by renormalization group techniques [1,3] and by projection methods [6]. The bose Hubbard modelwas also studied with Quantum Monte Carlomethods (QMC) by Batrouni et al. [2] in one dimension (1+1) and by K rauth and Trivedi [7] in two dimensions (2+1). In this contribution, we show that the phase diagram obtained from a strong-coupling expansion has the correct dependence on the dimensionality of the spatial lattice, and agrees with the QMC calculations (to within a few percent).

We study the minimal model which contains the key physics of the strongly interacting bose system { the competition between kinetic and potential energy elects:

$$H = \sum_{i,j}^{X} t_{ij} b_{j}^{Y} b_{j} \qquad \sum_{i}^{X} \hat{n}_{i} + \frac{1}{2} U \sum_{i}^{X} \hat{n}_{i} (\hat{n}_{i} - 1) \quad ; \quad \hat{n}_{i} = b_{i}^{Y} b_{i}$$
 (1)

where b_i is the boson annihilation operator at site i, t_{ij} is the hopping matrix element between the site i and j, U is the strength of the on-site repulsion, and is the chemical potential. The approximate form of the zero temperature (T = 0) phase diagram can be understood by starting from the strong-coupling or \atomic" limit [1,8,9]. In this limit, the kinetic energy vanishes ($t_{ij} = 0$) and every site is occupied by a xed number of bosons, n_0 . The ground-state boson occupancy (n_0) is then chosen in such a way as to minimize the on-site energy. If the chemical potential, $= (n_0 + 1)U$, is parametrized in terms of the deviation,

, from integer lling n_0 , then the on-site energy is E $(n_0) = U n_0 \frac{1}{2}U n_0 (n_0 1)$, and the energy to add a boson onto a particular site satis as E $(n_0 + 1)$ E $(n_0) = U n_0$. Thus for a nonzero , a nite amount of energy (gap) is required to move a particle through the lattice. The bosons are localized, producing a Mott insulator. This energy gap decreases with increasing strength of the hopping matrix elements until it vanishes and the bosons condense into the super uid phase. For = 0 the energy of the two dierent boson densities is degenerate [E $(n_0) = E (n_0 + 1)$] and no energy is needed to add or extract a particle; i.e., the compressibility is nite. As the strength of the hopping matrix elements increases, the range of the chemical potential about which the system is incompressible decreases. The Mott-insulator phase will completely disappear at a critical value of the hopping matrix elements.

We are interested in the determ ination of the phase boundary between the (incompressible) M ott insulator and the (compressible) super uid phase. A strong-coupling expansion for this boundary is determ ined by calculating both the energy of the M ott insulating phase and of a defect phase (which contains an extra hole or particle) in a perturbative expansion of the kinetic energy. At the point where the energy of the M ott phase is degenerate with the defect phase, the system becomes compressible, and, since there is no disorder, also super uid [1]. There are two distinct cases for the defect phase: < 0 corresponds to adding a boson to the M ott-insulator phase (with n_0 bosons per site); and > 0 corresponds to adding a hole to the M ott-insulator phase (with $n_0 + 1$) bosons per site. The phase boundary will depend on the number of bosons per site, n_0 , of the initial M ott insulator phase.

To zeroth order in t=U the M ott insulating state is given by

$$j_{M \text{ ott}}(n_0)i^{(0)} = \frac{y^N}{p_{n_0}!} \frac{1}{p_{n_0}!} b_i^{y_{n_0}} \mathcal{D}i$$
 (2)

where n_0 is the number of bosons on each site, N is the number of sites in the lattice and \mathfrak{P} i is the vacuum state. The defect phase is characterized by one additional particle (hole) which moves coherently throughout the lattice. To zeroth order in t=U the wave function for the \defect phase" is determined by degenerate perturbation theory:

$$\dot{j}_{\text{Def}}(n_0) \dot{i}_{\text{particle}}^{(0)} = \frac{1}{\frac{1}{n_0 + 1}} \int_{i}^{X} f_i b_i^y \dot{j}_{\text{Mott}}(n_0) \dot{i}^{(0)}
\dot{j}_{\text{Def}}(n_0) \dot{i}_{\text{hole}}^{(0)} = \frac{1}{\frac{1}{n_0}} \int_{i}^{X} f_i b_i \dot{j}_{\text{Mott}}(n_0) \dot{i}^{(0)}$$
(3)

where the f_i is the eigenvector of the hopping matrix t_{ij} with the lowest eigenvalue [10].

For sim plicity we will only consider hopping between the nearest neighbors of a hypercubic lattice in d-dimensions. The number of nearest neighbors is denoted by z=2d and the hopping matrix element by t; the minimum eigenvalue of the hopping matrix is zt. The many body version of standard Rayleigh-Schrodinger perturbation theory is employed throughout. To third order in t=U, the energy of the M ott state with n_0 bosons per site becomes

$$E_{M \text{ ott}}(n_0) = N$$
 $U n_0 \frac{1}{2} U n_0 (n_0 + 1) \frac{zt^2}{U} n_0 (n_0 + 1)$ (4)

which is proportional to the number of sites. Note that the odd-order terms vanish. The energy dierence between the Mott insulating phase and the defect phase with an additional particle (<0) satisfies

$$\begin{split} E_{\,D\,ef}^{\,\,(particle)}\,(n_0) \quad E_{\,M\,\,ott}\,(n_0) = \quad & \text{ $^{(particle)}$U } \quad zt(n_0+1) + \frac{zt^2}{U}\frac{n_0\,(5n_0+4)}{2} \quad \frac{z^2t^2}{U}n_0\,(n_0+1) \\ + \frac{t^3}{U^{\,2}}n_0\,(n_0+1) \quad (\ 2z^3 + \frac{25}{4}z^2 \quad 4z)n_0 + (\ z^3 + \frac{7}{2}z^2 \quad 2z) \end{split} \tag{5}$$

to third order in t=U; while the energy dierence between the M ott insulating phase and the defect phase with an additional hole (> 0) satisfies

$$\begin{split} E_{D\,\text{ef}}^{\,\text{(hole)}}\left(n_{0}\right) & E_{M\,\text{ott}}\left(n_{0}\right) = \\ & + \frac{t^{3}}{U^{2}}n_{0}\left(n_{0}+1\right) \left(2z^{3}+\frac{25}{4}z^{2}-4z\right)n_{0} + \left(z^{3}+\frac{11}{4}z^{2}-2z\right) \end{split} \tag{6}$$

These results have been verilled by small-cluster calculations on two and four-site clusters. Note that the energy dilerence in Eqs. (5) and (6) is independent of the lattice size N.

The phase boundary between the incompressible M of phase and the compressible super uid phase occurs when the energy dierence between the two dierent phases vanishes [11]. The two branches of the M of phase boundary meet when

$$(particle)(n_0) + 1 = (hole)(n_0)$$
: (7)

The additional one on the left hand side arises because is measured from the point $=U=n_0$. Equation (7) may be used to estimate the critical value of the hopping matrix element, $t_{critical}(n_0)$, beyond which no Mott-insulator phase exists.

In one dim ension, the upper boundary of the M ott insulator lobe (with a particle density of n_0) is given by

to third order in t=U, and the lower boundary is given by

The slope of the phase boundaries about the point $= n_0 U$ are equal in magnitude to rst order [$\lim_{t \to 0} \frac{d}{dt}$ particle $(n_0; t=U) = \lim_{t \to 0} \frac{d}{dt}$ hole $(n_0+1; t=U)$], but change in magnitude as a function of the density (n_0) , in plying that the M ott-phase lobes always have an asymmetrical shape.

The strong-coupling expansion for the t, phase diagram in one dimension is compared to the QMC results of Batrouni et al. [2] in Figure 1. The solid lines indicate the phase boundary between the Mott-insulator phase and the super uid phase at zero temperature as calculated from Eq. (8) and Eq. (9). The squares are the results of the QMC calculation at a small but nite temperature T = U = 2 [2]. Note that the overall agreement of the two calculations is excellent. For example, the critical value of the chemical potential for the rst lobe $(n_0 = 1)$ satisfies $c_{critical} = 0.215$, while the QMC calculations found $c_{critical} = 0.215 = 0.01$ [2]. A closer examination shows that the rst lobe $c_{color} = 0.215$ of the Mott-insulator phase becomes more stable at higher temperatures [5].

It is known from the scaling theory of Fisher et al. [1] that the phase transition at the tip of the M ott lobe is in the universality class of the (d+1) dim ensional X Y m odel. A lthough a

nite-order perturbation theory cannot describe the physics of the tricritical point correctly, it turns out that the density uctuations dom inate the physics of the phase transition even close to the tricritical point. Note how the Mott lobes have a cusp-like structure in one dimension, m im icking the Kosterlitz-Thouless behavior of the critical point.

Figure 2 presents the strong-coupling expansion for the t, phase diagram in two dimensions. For comparison, the tricritical point of the rst Mott-insulator lobe as obtained by the QMC simulations of K rauth and Trivedi [7] is marked with a solid square. Their numerical calculation gives a critical value of (t=U)_{critical} = 0:122 0:01, whereas our calculation yields (t=U)_{critical} 0:136 which is in reasonable agreement. As already mentioned above we cannot hope to describe the physics close to tricritical point with our approach, but note that the qualitative shape of the Mott lobes has changed from one dimension to two dimensions, mimicking the \smooth" critical behavior of the XY model in three or larger dimensions.

Finally the strong-coupling expansion is compared to the exact calculation in in nite dimensions [1]. In in nite dimensions, the hopping matrix element must scale inversely with the dimension [12], t = t = d, t = n ite, producing the mean eld theory of Ref. [1]. In Figure 3 the strong-coupling expansion (solid line) is compared to the exact solution (dashed line). Even in in nite dimensions, the agreement of the strong-coupling expansion with the exact results is quite good.

We have repeatedly compared a strong-coupling expansion to the numerical QMC simulations for the incompressible-compressible phase boundary of the bose Hubbard model. A mean-eld treatment of the bose Hubbard model (e.g. [1,5]) cannot capture the physics of the one dimensional system which is completely dominated by uctuations. The dimensionality only enters as a trivial prefactor in integrals over the phase space. For this reason, mean-eld theories will always give a concave shape to the Mott-insulator lobes independent of the dimension. A strong-coupling expansion, on the other hand, easily distinguishes the shape difference from one dimension to higher dimensions and shows that a proper treatment of density uctuations is critical in determining the Mott-insulator to super uid transition.

In conclusion we have described an analytical method to accurately calculate the phase diagram of the bose Hubbard model in any dimension. Extensions of these techniques to include disorder will be presented separately.

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FIGURES

- FIG.1. The t, phase diagram of the bose Hubbard model in one dimension (d = 1). The solid lines give the phase boundaries of the M ott insulator to the super uid state as determined from a third-order strong-coupling calculation. The squares are the result of the QMC calculation of B atrouniet al. [2].
- FIG. 2. The t, phase diagram of the bose Hubbard model in two dimensions (d = 2). The solid lines give the phase boundaries of the M ott insulator to the super uid state as determined from a third-order strong-coupling calculation. The point indicates the tricritical point as determined by the QMC calculation of K rauth and Trivedi [7].
- FIG. 3. The t, phase diagram of the bose Hubbard model in in nite dimensions (d! 1). The solid lines give the phase boundaries of the Mott insulator to the super uid state as determined from a third-order strong-coupling calculation. The dashed lines are the result of the mean eld calculation of Fisher et al. [1].